## NSN 5961-00-817-6403

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View Online at https://aerobasegroup.com/nsn/5961-00-817-6403 **Inclosure Material:** Metal **Overall Length:** 0.650 inches **Overall Diameter:** 0.850 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Gate **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.250 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 28.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 500.00 milliamperes source cutoff current and 12.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 4 tab, solder lug **Specification Data:** 80131-release2571 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

**Fiig:** A110a0

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